CPH6102



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Bipolar Transisitor -50V, -1A, Low VCE(sat) PNP Single CPH6

Applications

· DC-DC converter, relay drivers, lamp drivers, motor drivers, strobes

Features

- · Adoption of FBET, MBIT processes
- · Large current capacity
- · Low collector to emitter saturation voltage
- · High-speed switching
- Ultrasmall package permitting applied sets to be made small and slim (0.9mm)
- · High allowable power dissipation

Specifications

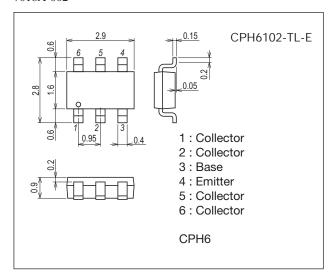
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	VCBO		-60	V
Collector to Emitter Voltage	VCEO		-50	V
Emitter to Base Voltage	V _{EBO}		-5	V
Collector Current	IC		-1.0	Α
Collector Current (Pulse)	ICP		-2	А
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7018A-002



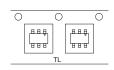
Product & Package Information

• Package : CPH6

• JEITA, JEDEC : SC-74, SOT-26, SOT-457

 \bullet Minimum Packing Quantity $\,$: 3,000 pcs./reel

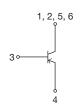
Packing Type: TL



Marking



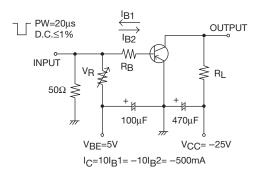
Electrical Connection



Electrical Characteristics at Ta=25°C

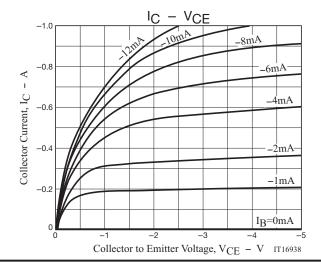
Parameter	Symbol	Conditions	Ratings			Unit
Parameter		Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} = -50V, I _E =0A			-100	nA
Emitter Cutoff Current	IEBO	V _{EB} = -4V, I _C =0A			-100	nA
DC Current Gain	h _{FE} 1	V _{CE} = -2V, I _C = -100mA			560	
DC Current Gain	h _{FE} 2	V _{CE} = -2V, I _C = -1A	30			
Gain-Bandwidth Product	fŢ	V _{CE} = -10V, I _C = -50mA		150		MHz
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		12		pF
Collector to Emitter Saturation Voltage	V _{CE} (sat)	I _C = -500mA, I _B = -50mA		-180	-500	mV
Base to Emitter Saturation Voltage	V _{BE} (sat)	I _C = -500mA, I _B = -50mA		-0.9	-1.2	V
Collector to Base Breakdown Voltage	V(BR)CBO	IC= -10μA, IE=0A	-60			V
Collector to Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-50			V
Emitter to Base Breakdown Voltage	V(BR)EBO	I _E = -10μA, I _C =0A	-5			V
Turn-ON Time	ton			40		ns
Storage Time	tstg	See specified Test Circuit.		300		ns
Fall Time	tf			30		ns

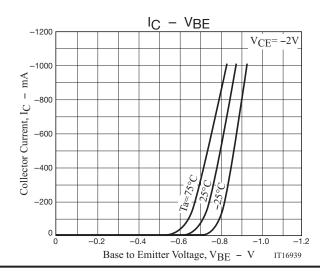
Switching Time Test Circuit

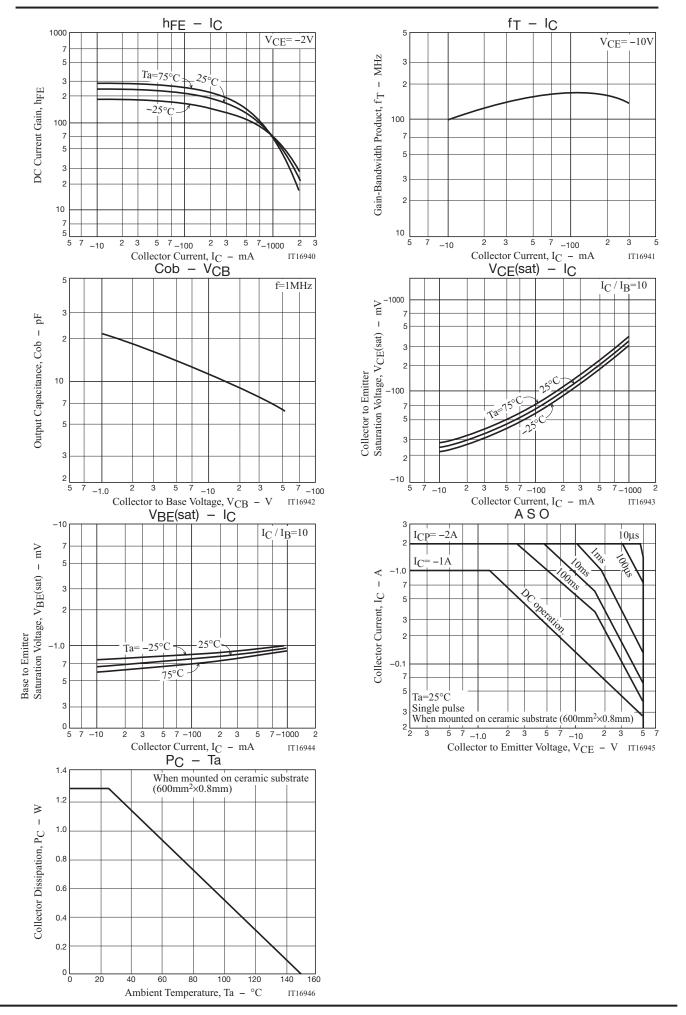


Ordering Information

Device	Package	Shipping	memo	
CPH6102-TL-E	CPH6	3,000pcs./reel	Pb Free	

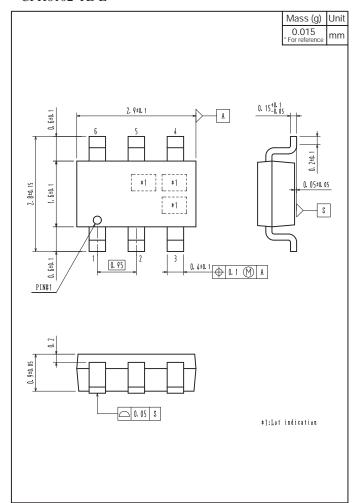




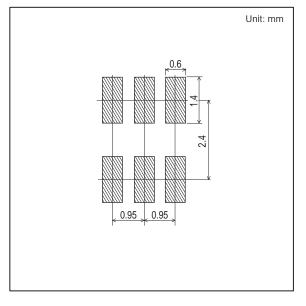


Outline Drawing

CPH6102-TL-E



Land Pattern Example



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